

SANGDEST MICROELECTRONICS SDUR560 SDURB560 SDURF560

Technical Data Data Sheet N1282, Rev. - **Green Products**

SDUR560/SDURB560/SDURF560 ULTRAFAST PLASTIC RECTIFIER

Applications:

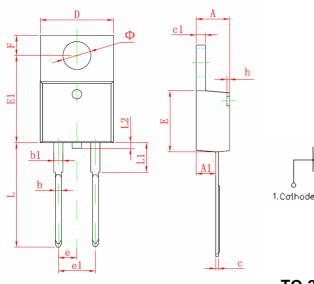
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm



Ourse had	Dimensions In Millimeters		
Symbol	Min	Мах	
А	4.470	4.670	
A1	2.520	2.820	
b	0.710	0.910	
b1	1.170	1.370	
с	0.310	0.530	
c1	1.170	1.370	
D	10.010	10.310	
E	8.500	8.900	
E1	12.060	12.460	
е	2.540) TYP	
e1	4.980	5.180	
F	2.590	2.890	
h	0.000	0.300	
L	13.400	13.800	
L1	3.560	3.960	
L2		1.000	
Φ	3.735	3.935	

TO-220AC

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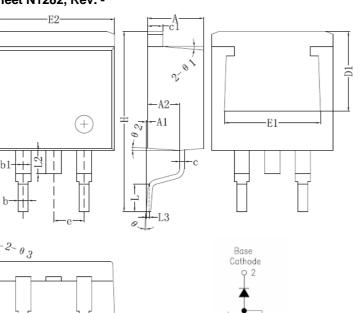
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b1



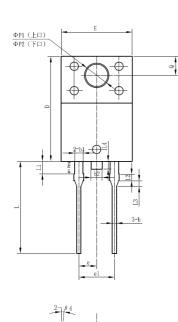
Symbol	Dimensions in			
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8 °	
e1		5°		
e2		4°		
e3		4°		

D² PAK

93

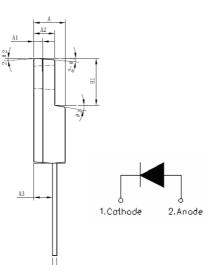
Anode

01 N/C



- 0 -

-F



SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3 20
A3 b	2.50	2.70	2.90
b	0.50 1.10	0.60	2.90 0.75 1.35
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
С	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16 2.55	10.36
е	-	2.55	-
e1	-	5.10	-
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60 0.80	1.80	2.00
L2	0.80	1.00	1.20
L1 L2 L3	0.60	0.80	2.00 1.20 1.00
L4	-	1.10	1.50
ΦΡ1(上口)	3.30	3.50	3.70
ΦΡ2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		5° 4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

ITO-220AC(HD)

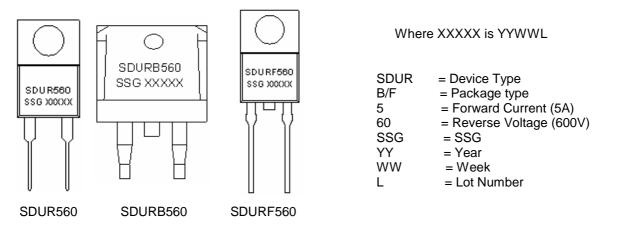
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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDUR560	TO-220AC (Pb-Free)	50pcs / tube
SDURB560	D² PAK (Pb-Free)	800pcs / reel
SDURF560	ITO-220AC (Pb-Free)	50 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	600	V
Max. Average Forward Current	lo _(AV)	50% duty cycle @Tc=100℃, rectangular wave form	5	А
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	50Hz, Half Sine wave	80	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _F	@ 5A, Pulse, T _J = 25℃	1.55	V
	V _{F2}	@ 5A, Pulse, T _J = 125°C	1.45	V
Max. Reverse Current	I _R	$@V_{R} = rated V_{R}$	5	μA
		T _J = 25℃		
	I _R	$@V_{R} = rated V_{R}$	500	μA
		T _J = 125℃		
Max. Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A, and I_{rm} =250mA	50	ns

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	SDUR560	SDURB560	SDURF560	Units
Junction Temperature	TJ		-55 to +150		°C
Storage Temperature	T _{stg}	-55 to +150			°C
Maximum Thermal Resistance Junction to Case(per leg)*	R _{θJC}	2.3	2.3	4.2	K/W
Approximate Weight	wt	1.8	1.85	1.8	g
Case Style	TO-220AC/ D ² PAK/ ITO-220AC				

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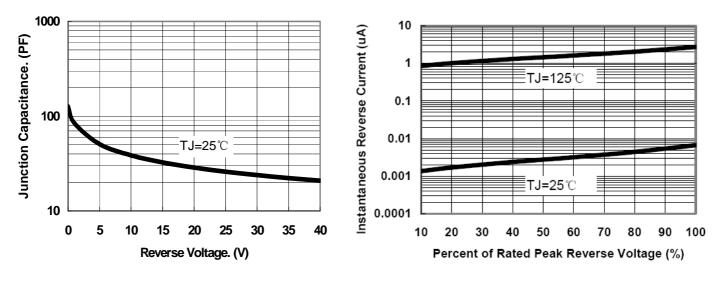


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

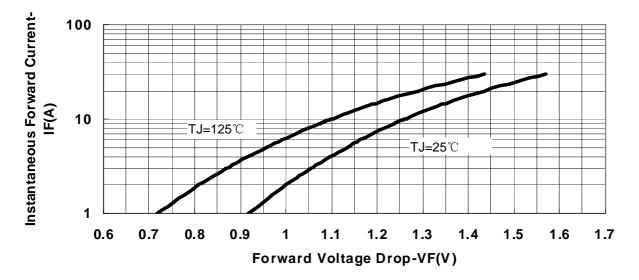


Fig.3-Typical Forward Voltage Drop Characteristics



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